

PRODUCT FEATURES

- QSFP+ MSA compliant
- 4x10Gb/s electrical interface
- Supports 41.2Gb/s aggregate bit rate
- Up to 10km transmission on single mode fiber
- LC duplex connector
- Hot-pluggable QSFP+ footprint
- 4-lane DFB and 4-lane PIN
- Commercial case temperature: 0°C to 70°C
- Single 3.3V power supply
- Maximum power consumption 3.5 Watts

APPLICATIONS

- 40GBASE-LR4 Ethernet
- Data Center Interconnect

COMPLIANCE

- QSFP+ MSA
- SFF-8436
- IEEE802.3ba
- RoHS2.0

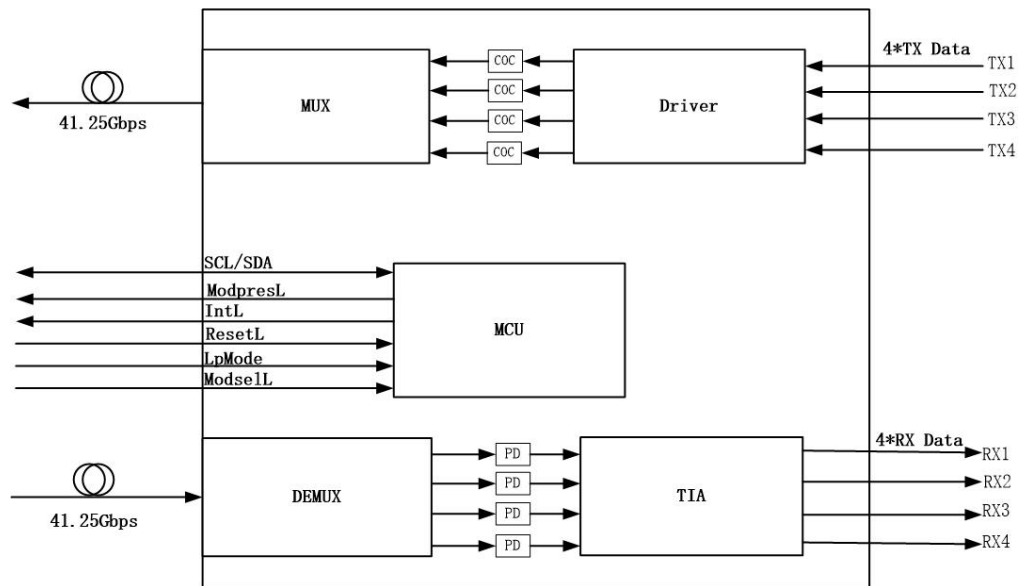
Ordering information

Part Number	Data Rate (Gb/s)	Media	Wavelength(nm)	Operating distance(km)	Temperature(°C)
IP-EALK10B31C	41.2	SMF	CWDM	10	0~70

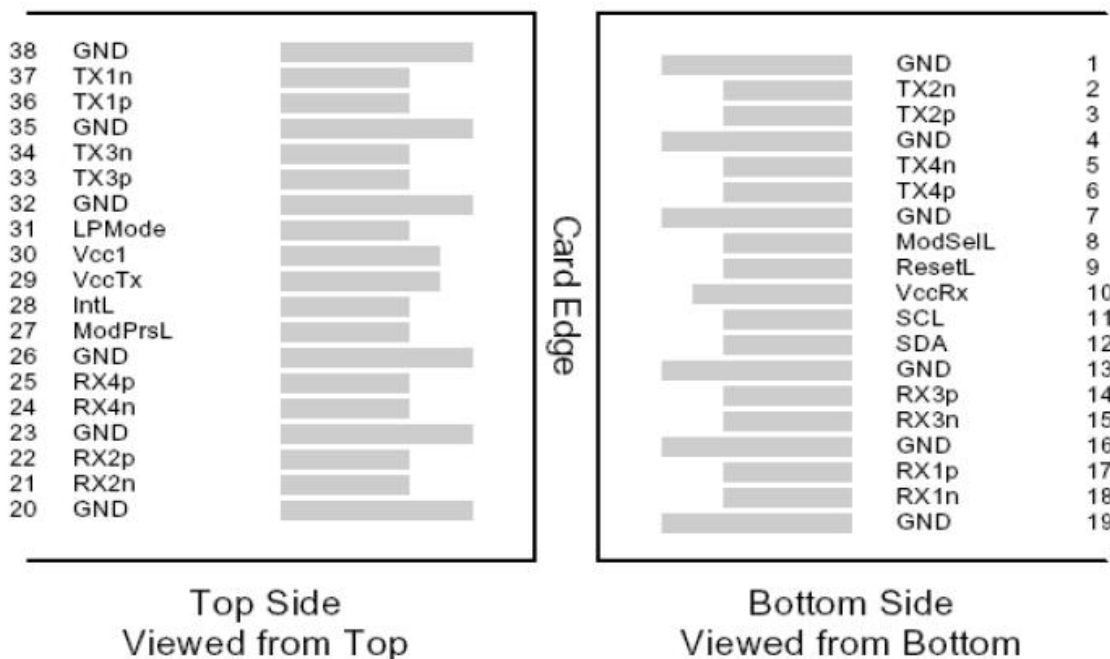
PRODUCT DESCRIPTION

IP-EALK10B31C is designed for 10km optical communication applications. This module contains 4-lane DFB optical transmitter, 4-lane optical receiver and module management block including 2 wire serial interfaces. The optical signals are multiplexed to a single-mode fiber through an industry standard LC connector.

1. Block Diagram



2. Pin Diagram



QSFP+ MSA-compliant 38-pin connector

3. Pin Descriptions

Pin	Symbol	Name/Description	Notes
1	GND	Ground	1
2	Tx2n	Transmitter Inverted Data Input	
3	Tx2p	Transmitter Non-Inverted Data Input	
4	GND	Ground	1
5	Tx4n	Transmitter Inverted Data Input	
6	Tx4p	Transmitter Non-Inverted Data Input	
7	GND	Ground	1
8	ModSe1L	Module Select	
9	ResetL	Module Reset	
10	Vcc Rx	+3.3V Power supply receiver	
11	SCL	2-wire serial interface clock	
12	SDA	2-wire serial interface data	
13	GND	Ground	1
14	Rx3p	Receiver Non-Inverted Data Output	
15	Rx3n	Receiver Inverted Data Output	
16	GND	Ground	1
17	Rx1p	Receiver Non-Inverted Data Output	
18	Rx1n	Receiver Inverted Data Output	
19	GND	Ground	1
20	GND	Ground	1
21	Rx2n	Receiver Inverted Data Output	
22	Rx2p	Receiver Non-Inverted Data Output	
23	GND	Ground	1
24	Rx4n	Receiver Inverted Data Output	
25	Rx4p	Receiver Non-Inverted Data Output	
26	GND	Ground	1
27	ModPrSL	Module Present	
28	IntL	Interrupt	
29	VccTx	+3.3V Power supply transmitter	
30	Vcc1	+3.3V Power Supply	
31	LPMODE	Low Power Mode	
32	GND	Ground	1
33	Tx3p	Transmitter Non-Inverted Data Input	
34	Tx3n	Transmitter Inverted Data Input	
35	GND	Ground	1
36	Tx1p	Transmitter Non-Inverted Data Input	
37	Tx1n	Transmitter Inverted Data Input	
38	GND	Ground	1

Note:

1. Circuit ground is internally isolated from chassis ground.

4. Absolute Maximum Ratings

It has to be noted that the operation in excess of any individual absolute maximum ratings might cause permanent damage to this module.

Parameter	Symbol	Min	Typical	Max	Unit	Note
Maximum Supply Voltage	V_{cc}	0		3.6	V	
Storage Temperature	T_s	-40		85	°C	
Relative Humidity	RH	5		85	%	
Damage threshold, per lane	P_{dam}	3.4			dBm	

5. Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Max	Unit	Note
Operating Case Temperature	T_{case}	0		70	°C	
Supply Voltage	V_{cc}	3.135	3.3	3.465	V	
Relative Humidity	RH	5		85	%	
Data Rate (Optical)	DRO		4*10.3125		Gbps	
Data Rate (Electrical)	DRE		4*10.3125		Gbps	
Link Distance				10	km	

6. Electrical Characteristics

40GBASE-LR4 Operation (EOL, TOP = 0 ~70 °C , V_{cc} = 3.135 to 3.465 V)

Notes:

Parameter	Symbol	Min	Typical	Max	Unit	Notes
Power Dissipation				3.5	W	
Supply Current	I_{cc}			1.1	A	1
Transmitter						
Data Rate, each lane			10.3125		Gbps	2
Differential Voltage pk-pk	V_{pp}			900	mV	
Input differential impedance	R_{in}		100		Ohm	
Differential Termination Resistance Mismatch				10	%	3
Receiver						
Data Rate, each lane			10.3125		Gbps	2
Output differential impedance	R_{out}		100		Ohm	
Differential Termination Resistance Mismatch				10	%	3
Differential output voltage	$V_{out, pp}$			900	mV	

1. Steady state.
2. For 40GBASE-LR4 application.
3. At 1 MHz.

7. Optical Characteristics

40GBASE-LR4 Operation (EOL, TOP = 0 ~70°C , V_{cc} = 3.135 to 3.465 V)

Parameters	Symbol	Min	Typical	Max	Unit	Notes
Transmitter						
Signal Speed per Lane	BR	10.3125 ± 100 ppm			Gb/s	
Transmit wavelength	λ_0	1264.5	1271	1277.5	nm	
	λ_1	1284.5	1291	1297.5	nm	
	λ_2	1304.5	1311	1317.5	nm	
	λ_3	1324.5	1331	1337.5	nm	
Side-Mode Suppression Ratio	SMSR	30			dB	
Total Average Launch Power	P_{total}			8.3	dBm	
Average launch power, each lane	P_{out}	-7		2.3	dBm	
Difference in launch power between any two lanes (Average and OMA)				6.5	dB	
Launch power OFF per lane				-40	dBm	
Transmitter and Dispersion Penalty (TDP), each lane	TDP			2.6	dB	
Transmitter OFF Output Power	P_{Off}			-30	dBm	
Optical Modulation Amplitude minus TDP, each lane		-4.8			dBm	
Extinction Ratio (ER)	ER	3.5			dB	
Transmitter eye mask definition {X1, X2, X3, Y1, Y2, Y3}	{0.25, 0.4, 0.45, 0.25, 0.28, 0.4}					1
Mask margin		15			%	1
Receiver						
Signal Speed per Lane	BR	10.3125 ± 100 ppm			Gb/s	
Receive wavelength	λ_0	1264.5	1271	1277.5	nm	
	λ_1	1284.5	1291	1297.5	nm	
	λ_2	1304.5	1311	1317.5	nm	
	λ_3	1324.5	1331	1337.5	nm	
Damage threshold, each lane	P_{min}	3.3			dBm	
Average receive power, each lane		-13.7		2.3	dBm	
Receiver Sensitivity (OMA) per Lane				-11.5	dBm	2
Receive power, each lane(OMA)				3.5	dBm	
Receiver reflectance				-26	dB	
LOS Assert		-30			dBm	
LOS De-Assert				-12.5	dBm	
LOS Hysteresis		0.5		6	dB	

Notes:

1.Hit ratio 5×10^{-5} .

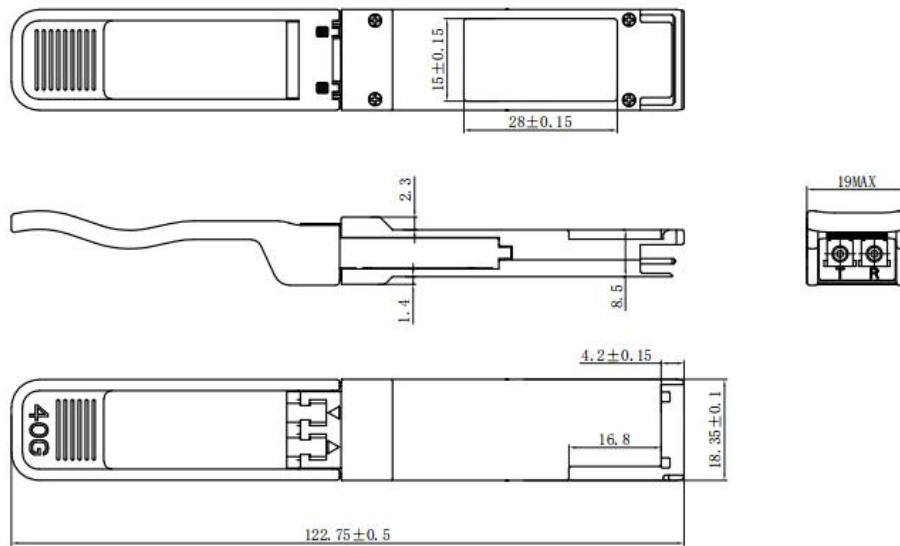
2.Sensitivity is specified at BER@1E-12.

8. Digital Diagnostic Monitoring Functions

IP-EALK10B31C support the I2C-based Diagnostic Monitoring Interface (DMI) defined in document SFF-8436. The host can access real-time performance of transmitter and receiver optical power, temperature, supply voltage and bias current.

Parameter	Accuracy	Unit
Case Temperature	± 3	$^{\circ}\text{C}$
Supply Voltage	$\pm 3\%$	V
Tx Bias Current	$\pm 10\%$	mA
Tx Optical Power	± 3	dB
Rx Optical Power	± 3	dB

9. Mechanical Specifications



10. Regulatory Compliance

Feature	Reference	Performance
EMC	EN61000-3	Compatible with standards
Electrostatic Discharge (ESD)	IEC/EN 61000-4-2	Compatible with standards
Electromagnetic Interference (EMI)	FCC Part 15 Class B EN 55022 Class B (CISPR 22A)	Compatible with standards
Laser Eye Safety	FDA 21CFR 1040.10, 1040.11 IEC/EN 60825-1, EC/EN 60825-2	Class 1 laser product
Component Recognition	IEC/EN 60950, L 60950	Compatible with standards
RoHS	2021/65/EU	Compatible with standards

11. Contact Information

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12. Revision History

Version No.	Date	Description
1.0	June. 24, 2019	Preliminary datasheet
1.1	Oct. 8, 2021	Update contact Information
1.2	Jun. 6, 2022	Update mechanical specifications
1.3	Jun.30, 2024	Update contact information.